Conductivity of the classical two-dimensional electron gas

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We discuss the applicability of the Boltzmann equation to the classical two-dimensional electron gas. We show that in the presence of both the electron-impurity and electron-electron scattering the Boltzmann equation can be inapplicable and the correct result for conductivity can be different from the one obtained from the kinetic equation by a logarithmically large factor.

The description of kinetics of the classical electron gas in semiconductors is usually done with the help of the Boltzmann kinetic equation [1]

$$\frac{\partial n_{\boldsymbol{p}}(\boldsymbol{r},t)}{\partial t} + \boldsymbol{v} \cdot \frac{\partial n_{\boldsymbol{p}}(\boldsymbol{r},t)}{\partial \boldsymbol{r}} + e\boldsymbol{E} \cdot \frac{\partial n_{\boldsymbol{p}}(\boldsymbol{r},t)}{\partial \boldsymbol{p}}$$
$$= I_{imp}(n_{\boldsymbol{p}}(\boldsymbol{r},t)) + I_{ee}(n_{\boldsymbol{p}}(\boldsymbol{r},t)) + I_{ph}(n_{\boldsymbol{p}}(\boldsymbol{r},t))$$
(1)

where $n_{p}(\mathbf{r}, t)$ is the electron distribution function, \mathbf{E} is the external electric field, \mathbf{v} and \mathbf{p} are the electron velocity and momentum, and I_{imp}, I_{ee} and I_{ph} are the electron-impurity, electron-electron and electron-phonon scattering integrals which are characterized by the relaxation times τ_i , τ_e and τ_{ph} respectively.

At low enough temperatures T when $\tau_i \ll \tau_{ph}, \tau_e$, the conductivity of the sample is determined by the electronimpurity scatterings and is given by the Drude formula

$$\sigma_0 = e^2 D\nu \tag{2}$$

Here $D = v_F^2 \tau_i/2$ (where v_F is the Fermi velocity, $\tau_i = 1/v_F N_i a$, N_i is the impurity concentration and a is the amplitude of the electron-impurity scattering), and ν is the electron density of states at the Fermi level. To be concrete, we consider the case of a degenerate electron gas, though our results are of a general character. Eq. (2) also holds in the case of intermediate temperatures when $\tau_{ph} \gg \tau_i \gg \tau_e$. Indeed, since the electron-electron scatterings conserve the total momentum in the electron system, they do not contribute directly to the resistance of the system.

The form of I_{imp} in Eq. (1) is a result of a procedure in which averaging over realizations of the random impurity potential is done before solving the equation of motion. The criteria of applicability of the conventional Boltzmann kinetic equation (1) correspond to the absence of correlations between subsequent scattering events. This leads us to a requirement that the electron gas is weakly interacting

$$\tau_i, \tau_e \gg t_{coll} \tag{3}$$

where t_{coll} is the the collision time, which is estimated as a/v in classical mechanics, and as $\frac{\hbar}{\epsilon}$ in quantum mechanics (ϵ is the characteristic electron energy). It has been shown [2] that in the two-dimensional case even under conditions (3) the quantum interference corrections to the Drude formula logarithmically diverge as temperature T goes to zero. This means that in this case the kinetic equation (1) is not applicable at small T.

In this article we study the case of high enough temperatures when the quantum interference corrections can be neglected. The classical corrections to Eq. (2) associated with correlations between subsequent scatterings were considered in [3,4] in the framework of the Lorentz gas model. It was shown that in the two-dimensional case correlational corrections to the diffusion coefficient and to the conductivity are small, but nonanalytical functions of the concentration of scatterers N_i .

We consider in this article the case of a twodimensional electron gas with the mean free path $l_e = v_F \tau_e$ much smaller than the average distance between the impurities: $l_e \ll N_i^{-1/2}$. We show that under conditions (3) a combination of electron-electron and electronimpurity scatterings can lead to big correlational corrections to the Drude formula and that the correct expression for the conductivity of the system is

$$\sigma = \sigma_0 \left(1 + \frac{av_F}{2\pi\eta} \ln \frac{1}{N_i^{1/2} l_e} \right) \tag{4}$$

where η is the kinematic viscosity of the electron liquid, which is estimated for a Fermi liquid as $\eta \sim v_F l_e$. Eq. (4) differs from Eq. (2) by a logarithmically large factor, provided

$$\frac{av_F}{2\pi\eta}\ln\frac{1}{N_i^{1/2}l_e}\gg 1.$$

On distances from impurities larger than l_e , the motion of the electron system can be described by the Navier-Stokes hydrodynamic equation which can be derived from Eq. (1) with $I_{imp} = 0$ [6]. In this case the elastic scatterers should be described by a random potential and the averaging over the random realizations of the potential should be done after solving the Navier-Stokes equation. This should in principle give a result for conductivity that is different from the one implied by Eq. (1). The two approaches are equivalent in the approximation which assumes the variation of the hydrodynamic velocity between impurities to be small.

The idea of this paper is that, in fact, in the twodimensional case the hydrodynamic velocity of electrons is a significantly nonuniform function of coordinates: the velocity near impurities is much smaller than inbetween them. This is in contrast to the three-dimensional case where the spatial variation of the velocity is small and Eqs. (1), (2) are applicable. The reason for the significant nonuniformity of the velocity field is connected to the Stokes paradox [5]: in the presence of an obstacle bypassed by the fluid, the solution of the linearized Navier-Stokes equation in the two-dimensional case grows logarithmically with the distance from the obstacle. This means the absence of a bounded solution. In our case the finite concentration of scatterers provides a bound on the magnitude of the velocity field. However, the magnitude of the average velocity of electrons induced by the electric field turns out to be logarithmically bigger than that which follows from Eq. (1).

In the approximation linear in E, the Navier-Stokes equation has the form

$$-\nabla p + \mu \Delta \boldsymbol{u} + ne\boldsymbol{E} - \sum_{i} \boldsymbol{f} \delta(\boldsymbol{r} - \boldsymbol{r}_{i}) = 0 \qquad (5)$$

Here *n* is the electron concentration, $\mu = mn\eta$ is the dynamic viscosity of the electron fluid (where *m* is the electron mass), and \mathbf{r}_i are coordinates of impurities labeled by the index "i". The last term in Eq. (5) is associated with the force on the fluid by the i-th impurity, whose radius is much smaller than l_e . Therefore the value of the force \mathbf{f} can be estimated assuming that to zeroth order in a/l_e the distribution function of the electrons near the *i*-th impurity ($|\mathbf{r}-\mathbf{r}_i| \leq l_e$) is an equilibrium one with the average velocity $\mathbf{u}(\mathbf{r}_i)$. (In the following we will assume that all $\mathbf{u}(\mathbf{r}_i) \sim \mathbf{u}_0$ are of the same order.) Consequently we have [6]

$$\boldsymbol{f} = n p_F a \boldsymbol{u}_0. \tag{6}$$

In the stationary case the conservation of the total momentum of the system gives

$$e\boldsymbol{E} = \boldsymbol{f}N_i/n. \tag{7}$$

Far from the position of impurities $(|\mathbf{r} - \mathbf{r}_i| \gg l_e)$ the electron liquid can be considered as an incompressible one. The continuity equation for an incompressible liquid

$$\nabla \cdot \boldsymbol{u} = 0$$

and the Navier-Stokes equation (5) have a solution for the pressure and the velocity

$$\boldsymbol{u}(\boldsymbol{r}) = C\hat{x} + \hat{x}\frac{C_0}{2}\ln r - \frac{C_0}{4}(\hat{r}\cos\theta + \hat{\theta}\sin\theta)$$
$$p(r) = p_0 - \mu C_0 \frac{\cos\theta}{r}$$
(8)

where $C_0 = \frac{f}{2\pi\mu}$, \hat{r} and $\hat{\theta}$ are unit basis vectors of the cylindrical coordinate system and the x-axis (with the unit vector \hat{x}) is oriented parallel to the electric field.

The value of the coefficient C is determined using $\boldsymbol{u}(r = l_e, \theta = \pi) = \boldsymbol{u}_0$ and Eqs. (6), (7) and (8):

$$C = \frac{\sigma_0 E}{ne} (1 - \frac{av_F}{4\pi\eta} \ln l_e).$$

As a result, the spatially averaged velocity $\bar{\boldsymbol{u}}$ of the electronic flow is

$$\bar{\boldsymbol{u}} = \frac{\sigma_0 \boldsymbol{E}}{ne} (1 + \frac{av_F}{2\pi\eta} \ln \frac{1}{N_i^{1/2} l_e}).$$

Expressing the current density as $j = ne\bar{u}$, the electric conductivity Eq. (4) is obtained.

The calculations presented above assumed that the viscosity of the electron gas is a well-defined quantity. On the other hand it is well known that the fluctuational corrections to the viscosity of a 2D neutral liquid diverge [7], which means that hydrodynamic equations are nonlocal in two dimensions. This fact was pointed out in [8]and discussed in the most complete form in [9]. Below we present a trivial generalization of the procedure [9] to estimate fluctuational corrections to the viscosity of the two-dimensional charged electron liquid. In this case the low-lying collective excitations are plasmons and the fluctuations of the charge and of the hydrodynamic velocity can be described as a combination of plasmon excitations with different wave vectors \boldsymbol{q} . The real part of the plasmon frequency is [10] $\omega_{\boldsymbol{q}} = \sqrt{2\pi n e^2 |\boldsymbol{q}|/m}$, where \boldsymbol{q} is the plasmon momentum. Since the imaginary part of the frequency $\omega_{\boldsymbol{q}}' = \eta |\boldsymbol{q}|^2/2$ is proportional to $|\boldsymbol{q}|^2$ $(\eta = \mu/mn$ is the kinematic viscosity of the liquid), fluctuations with sufficiently low |q| have arbitrarily large mean free path and therefore plasmons are well-defined excitations. This is the physical reason why the fluctuational mechanism of viscosity is always the basic one at sufficiently small gradients and in samples with no elastically scattering potential. Since the phases of the thermal fluctuations are random it is convenient to introduce a distribution function of plasmon fluctuations n(q), normalized in such a way that the quantity $\int \frac{d\boldsymbol{q}}{(2\pi)^2} \omega(\boldsymbol{q}) n(\boldsymbol{q})$ is the average energy density of fluctuations. The flux of momentum associated with these excitations is [11]

$$\Pi_{ij} = -\int \frac{d\boldsymbol{q}}{(2\pi)^2} q_j \frac{\partial \omega_{\boldsymbol{q}}}{\partial q_i} n(\boldsymbol{q}) \tag{9}$$

The part of the distribution function of plasmons which is proportional to the gradient of the hydrodynamic velocity can be retrieved from the kinetic equation [9]

$$\frac{\partial \omega_{\boldsymbol{q}}}{\partial \boldsymbol{q}} \cdot \frac{\partial n_{\boldsymbol{u}}(\boldsymbol{q})}{\partial \boldsymbol{r}} = -(n(\boldsymbol{r}, \boldsymbol{q}) - n_{u}(\boldsymbol{q}))/\tau$$
(10)

where $\tau = \omega'^{-1}$ is the plasmon mean free time and $n_u(q)$ is the equilibrium Bose distribution function corresponding to a local hydrodynamic velocity u(r). At small ω

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and $|\boldsymbol{u}|$ one can approximate $n_{\boldsymbol{u}}(\boldsymbol{q}) \simeq \frac{T}{\omega_{\boldsymbol{q}}-\boldsymbol{q}\cdot\boldsymbol{u}(r)}$. Using Eq. (10) and expanding $n_{\boldsymbol{u}}(\boldsymbol{q})$ in \boldsymbol{u} , one can estimate from Eq. (9) the fluctuational contribution to the viscosity

$$\delta\eta \sim -\frac{1}{mn} \int (q \frac{\partial \omega_{\boldsymbol{q}}}{\partial q})^2 \tau \frac{\partial n_0(\boldsymbol{q})}{\partial \omega_{\boldsymbol{q}}} q dq \qquad (11)$$

(where $n_0(\mathbf{q}) = n_{\mathbf{u}=0}(\mathbf{q})$). Thus the fluctuational correction to the viscosity can be described only in terms of hydrodynamic quantities: viscosity and plasmon dispersion relation. In two-dimensional pure systems the expression Eq. (11) logarithmically diverges. However, in the presence of the elastically scattering potential the dispersion relation of plasmons which we used holds only at those frequencies for which the plasmon mean free time is shorter than the electron-impurity scattering time $\tau < \tau_i$. This determines a cut-off in Eq. (11). As a result, the fluctuational correction to the viscosity can be neglected provided

$$\delta\eta \sim \frac{T}{\mu} \ln(\frac{T}{E_F} \frac{\sigma_0}{e^2/\hbar}) \ll \eta.$$

In conclusion, we would like to stress that the existence of the large logarithmic factor in the Eq. (4) and the consequent inapplicability of the Boltzmann kinetic equation is a property of the two-dimensional problem. In the three-dimensional case the Stokes paradox does not exist, the difference between u_0 and \bar{u} is small and the Boltzmann kinetic equation can be applied.

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